Accepted Manuscript

Erbium (III) tris(8-hydroxyquinoline) doped zinc oxide interfacial layer for improved performance of polymer solar cells

B. Hari Babu, Chengkun Lv, Chengzhuo Yu, Pengqing Bi, Zhenchuan Wen, Xiaoyu Yang, Fenghong Li, Xiao-Tao Hao

PII: \$1566-1199(18)30370-7

DOI: 10.1016/j.orgel.2018.07.013

Reference: ORGELE 4793

To appear in: Organic Electronics

Received Date: 7 June 2018
Revised Date: 15 July 2018
Accepted Date: 16 July 2018

Please cite this article as: B.H. Babu, C. Lv, C. Yu, P. Bi, Z. Wen, X. Yang, F. Li, X.-T. Hao, Erbium (III) tris(8-hydroxyquinoline) doped zinc oxide interfacial layer for improved performance of polymer solar cells, *Organic Electronics* (2018), doi: 10.1016/j.orgel.2018.07.013.

This is a PDF file of an unedited manuscript that has been accepted for publication. As a service to our customers we are providing this early version of the manuscript. The manuscript will undergo copyediting, typesetting, and review of the resulting proof before it is published in its final form. Please note that during the production process errors may be discovered which could affect the content, and all legal disclaimers that apply to the journal pertain.



ACCEPTED MANUSCRIPT

Erbium (III) tris(8-hydroxyquinoline) doped zinc oxide interfacial layer for improved performance of polymer solar cells

B. Hari Babu¹, Chengkun Lv¹, Chengzhuo Yu², Pengqing Bi¹, Zhenchuan Wen¹, Xiaoyu Yang¹, Fenghong Li² and Xiao-Tao Hao^{1,3*}

¹School of Physics, State Key Laboratory of Crystal Materials, Shandong University, Jinan, Shandong 250100, China. ²State Key Laboratory of Supramolecular Structure and Materials, Institute of Theoretical Chemistry, Jilin University, Changchun 130012, P. R. China.

³ARC Centre of Excellence in Exciton Science, School of Chemistry, University of Melbourne, Parkville, Victoria 3010, Australia.

Abstract: Erbium (III) tris(8-hydroxyquinoline) ErQ complex is emerging as a class of novel luminescent material for interfacial engineering to improve the performance of organic solar cells (OSCs). In the present work, ErQ doped ZnO solution has successfully been prepared by the sol-gel route at room temperature as an electron transport layer for high efficient OSCs. The modified ErQ:ZnO films can yield not only higher electron mobility, good surface quality by the passivation of ZnO defects, but also slightly higher work-function and thereby shortening in the leakage current, which subsequently enhanced power conversion efficiency (PCE). As a result, the remarkable PCE increasing from 3.62 % to 4.26 % for poly(3-hexylthiophene):phenyl-C61-butyric acid methyl ester (P3HT:PC₆₁BM) and from 6.84 % to 7.95 % for polymer thieno [3,4-b] thiophene/benzodithiophene: [6,6] phenyl-C₇₁-butyric acid methyl ester (PTB7:PCB₇₁M) devices could be achieved upon an incorporating ErQ:ZnO interfacial layer.

*Corresponding author: haoxt@sdu.edu.cn Tel.: +86-531-58783287

Download English Version:

https://daneshyari.com/en/article/7699779

Download Persian Version:

https://daneshyari.com/article/7699779

Daneshyari.com